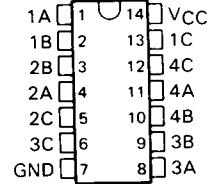


# TLC4016M, TLC4016I SILICON-GATE CMOS QUADRUPLE BILATERAL ANALOG SWITCH

D2922, JANUARY 1986—REVISED OCTOBER 1988

- High Degree of Linearity
- High On-Off Output Voltage Ratio
- Low Crosstalk Between Switches
- Low On-State Impedance . . . 50  $\Omega$  Typ at VCC = 9 V
- Individual Switch Controls
- Extremely Low Input Current

TLC4016M . . . J OR N PACKAGE  
TLC4016I . . . D OR N PACKAGE  
(TOP VIEW)



## description

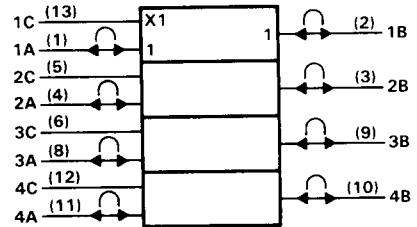
The TLC4016 is a silicon-gate CMOS quadruple analog switch designed to handle both analog and digital signals. Each switch permits signals with amplitudes up to 12 V peak to be transmitted in either direction.

Each switch section has its own enable input control. A high-level voltage applied to this control terminal turns on the associated switch section.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

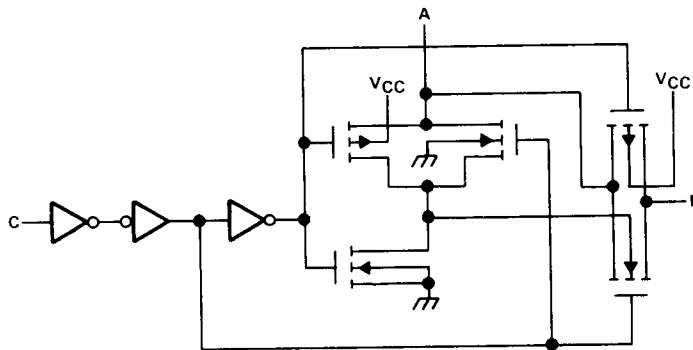
The TLC4016M is characterized for operation from  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ , and the TLC4016I is characterized from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

## logic symbol†



†This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)



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# TLC4016M, TLC4016I

## SILICON-GATE CMOS QUADRUPLE BILATERAL ANALOG SWITCH

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range (see Note 1)	-0.5 V to 15 V
Control-input diode current ( $V_I < 0$ or $V_I > V_{CC}$ )	$\pm 20$ mA
I/O port diode current ( $V_I < 0$ or $V_{I/O} > V_{CC}$ )	$\pm 20$ mA
On-state switch current ( $V_{I/O} = 0$ to $V_{CC}$ )	$\pm 25$ mA
Continuous current through $V_{CC}$ or GND pins	$\pm 50$ mA
Continuous total dissipation	see Dissipation Rating Table
Operating free-air temperature range: TLC4016M	-55°C to 125°C
TLC4016I	-40°C to 85°C
Storage temperature range	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or N package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package	300°C

NOTE 1: All voltages are with respect to ground unless otherwise specified.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	950 mW	7.6 mW/°C	608 mW	494 mW	N/A
J	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
N	1150 mW	9.2 mW/°C	736 mW	598 mW	230 mW

### recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, $V_{CC}$		2 <sup>†</sup>	5	12	V
I/O port voltage, $V_{I/O}$		0		$V_{CC}$	V
High-level input voltage, $V_{IH}$	$V_{CC} = 2$ V	1.5		$V_{CC}$	V
	$V_{CC} = 4.5$ V	3.15		$V_{CC}$	
	$V_{CC} = 9$ V	6.3		$V_{CC}$	
	$V_{CC} = 12$ V	8.4		$V_{CC}$	
Low-level input voltage, $V_{IL}$	$V_{CC} = 2$ V	0		0.3	V
	$V_{CC} = 4.5$ V	0		0.9	
	$V_{CC} = 9$ V	0		1.8	
	$V_{CC} = 12$ V	0		2.4	
Input rise time, $t_r$	$V_{CC} = 2$ V			1000	ns
	$V_{CC} = 4.5$ V			500	
	$V_{CC} = 9$ V			400	
Input fall time, $t_f$	$V_{CC} = 2$ V			1000	ns
	$V_{CC} = 4.5$ V			500	
	$V_{CC} = 9$ V			400	
Operating free-air temperature, $T_A$	TLC4016M	-55		125	°C
	TLC4016I	-40		85	

<sup>†</sup>With supply voltages at or near 2 V, the analog switch on-state resistance becomes very nonlinear. It is recommended that only digital signals be transmitted at these low supply voltages.

**TLC4016M, TLC4016I**  
**SILICON-GATE CMOS QUADRUPLE BILATERAL ANALOG SWITCH**

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted).

PARAMETER		TEST CONDITIONS	V <sub>CC</sub>	TLC4016M			TLC4016I			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
r <sub>SON</sub>	On-state switch resistance	I <sub>S</sub> = 1 mA, V <sub>A</sub> = 0 to V <sub>CC</sub> , See Figure 1	4.5 V	100	220	100	200	Ω		
			9 V	50	120	50	105			
			12 V	30	100	30	85			
			2 V	120	240	120	215			
			4.5 V	50	120	50	100			
			9 V	35	80	35	75			
		I <sub>S</sub> = 1 mA, V <sub>A</sub> = 0 or V <sub>CC</sub> , See Figure 1	12 V	20	70	20	60			
			4.5 V	10	20	10	20			
On-state switch resistance matching	V <sub>A</sub> = 0 to V <sub>CC</sub> , See Figure 1	9 V	5	15	5	15	Ω			
		12 V	5	15	5	15				
		2 V		±1		±1				
I <sub>I</sub>	Control input current	V <sub>I</sub> = 0 or V <sub>CC</sub>	to			±0.1	μA			
		V <sub>I</sub> = 0 or V <sub>CC</sub> , T <sub>A</sub> = 25°C	6 V			±0.1				
I <sub>SOFF</sub>	Off-state switch leakage current	V <sub>S</sub> = ±V <sub>CC</sub> , See Figure 2	5.5 V	±10	±600	±10	±600	nA		
			9 V	±15	±800	±15	±800			
			12 V	±20	±1000	±20	±1000			
I <sub>SON</sub>	On-state switch leakage current	V <sub>A</sub> = 0 or V <sub>CC</sub> , See Figure 3	5.5 V	±10	±150	±10	±150	nA		
			9 V	±15	±200	±15	±200			
			12 V	±20	±300	±20	±300			
I <sub>CC</sub>	Supply current	V <sub>I</sub> = 0 or V <sub>CC</sub> , I <sub>O</sub> = 0	5.5 V	2	40	2	20	μA		
			9 V	8	160	8	80			
			12 V	16	320	16	160			
C <sub>i</sub>	Input capacitance	A or B C	2 V to	15		15	pF			
			12 V	5	10	5		10		
C <sub>f</sub>	Feedthrough capacitance	A to B	V <sub>I</sub> = 0	2 V to	5	5	pF			
			12 V							

†All typical values are at T<sub>A</sub> = 25°C.

# TLC4016M, TLC4016I SILICON-GATE CMOS QUADRUPLE BILATERAL ANALOG SWITCH

switching characteristics over recommended operating free-air temperature range,  $C_L = 50$  pF (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CC}$	TLC4016M			TLC4016I			UNIT
			MIN	TYP†	MAX	MIN	TYP†	MAX	
$t_{pd}$	Propagation delay time, A to B or B to A	See Figure 4	2 V	25	75	25	62	ns	
			4.5 V	5	15	5	13		
			9 V	4	14	4	12		
			12 V	3	13	3	11		
$t_{on}$	Switch turn-on time	$R_L = 1$ k $\Omega$ , See Figures 5 and 6	2 V	32	150	32	125	ns	
			4.5 V	8	30	8	25		
			9 V	6	18	6	15		
			12 V	5	15	5	13		
$t_{off}$	Switch turn-off time	$R_L = 1$ k $\Omega$ , See Figures 5 and 6	2 V	45	252	45	210	ns	
			4.5 V	15	54	15	45		
			9 V	10	48	10	40		
			12 V	8	45	8	38		
$f_{co}$	Switch cutoff frequency (channel loss = 3 dB)		4.5 V	100		100		MHz	
			9 V	120		120			
$V_{OCF(PP)}$	Control feedthrough voltage to any switch, peak to peak	See Figure 7	4.5 V	350		350		mV	
	Frequency at which crosstalk attenuation between any two switches equals 50 dB	See Figure 8	4.5 V	1		1		MHz	

†All typical values are at  $T_A = 25^\circ\text{C}$ .

## PARAMETER MEASUREMENT INFORMATION

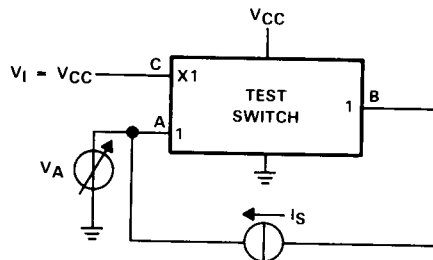
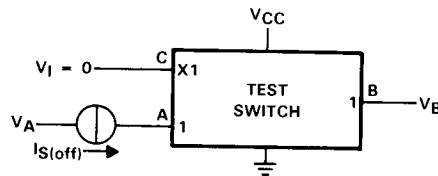


FIGURE 1. TEST CIRCUIT FOR ON-STATE RESISTANCE



$$V_S = V_A - V_B$$

CONDITION 1:  $V_A = 0$ ,  $V_B = V_{CC}$

CONDITION 2:  $V_A = V_{CC}$ ,  $V_B = 0$

FIGURE 2. TEST CIRCUIT FOR OFF-STATE SWITCH LEAKAGE CURRENT

PARAMETER MEASUREMENT INFORMATION

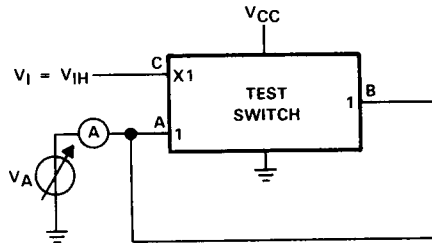


FIGURE 3. TEST CIRCUIT FOR ON-STATE SWITCH LEAKAGE CURRENT

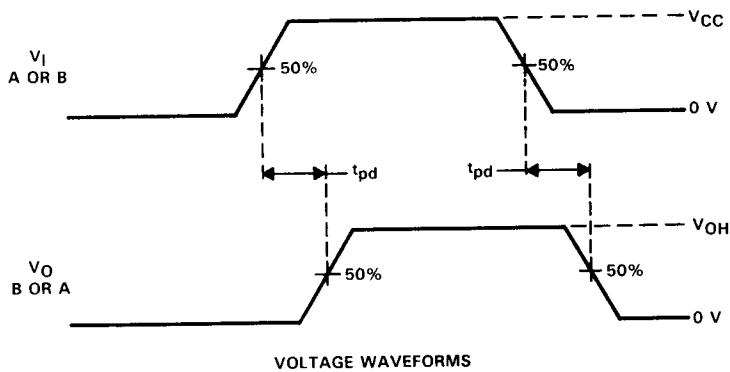
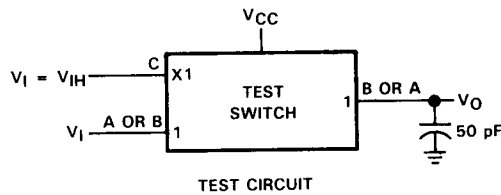
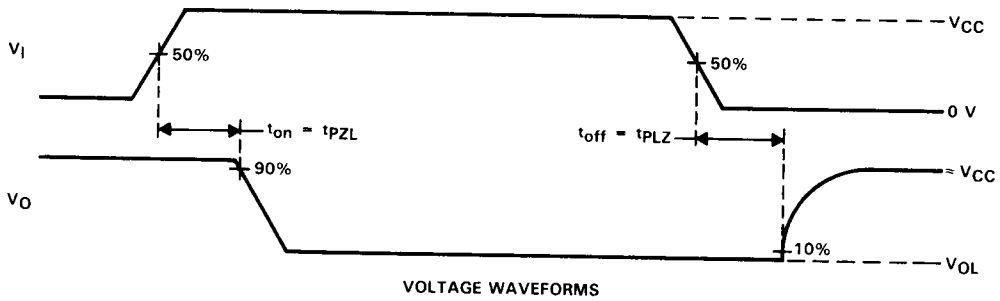
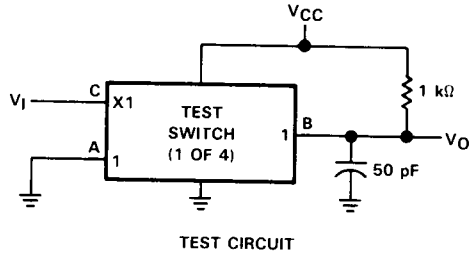


FIGURE 4. PROPAGATION DELAY TIME, SIGNAL INPUT TO SIGNAL OUTPUT

**TLC4016M, TLC4016I**  
**SILICON-GATE CMOS QUADRUPLE BILATERAL ANALOG SWITCH**

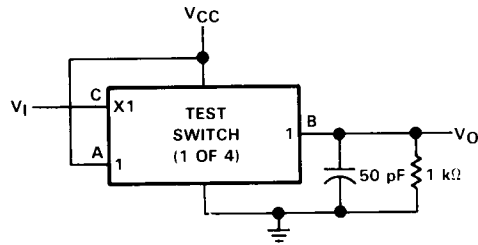
**PARAMETER MEASUREMENT INFORMATION**



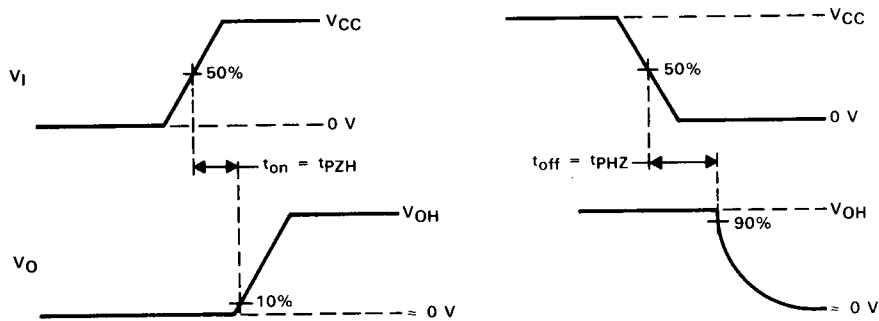
**FIGURE 5. SWITCHING TIME ( $t_{PZL}$ ,  $t_{PLZ}$ ), CONTROL TO SIGNAL OUTPUT**

TLC4016M, TLC4016I  
 SILICON-GATE CMOS QUADRUPLE BILATERAL ANALOG SWITCH

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT

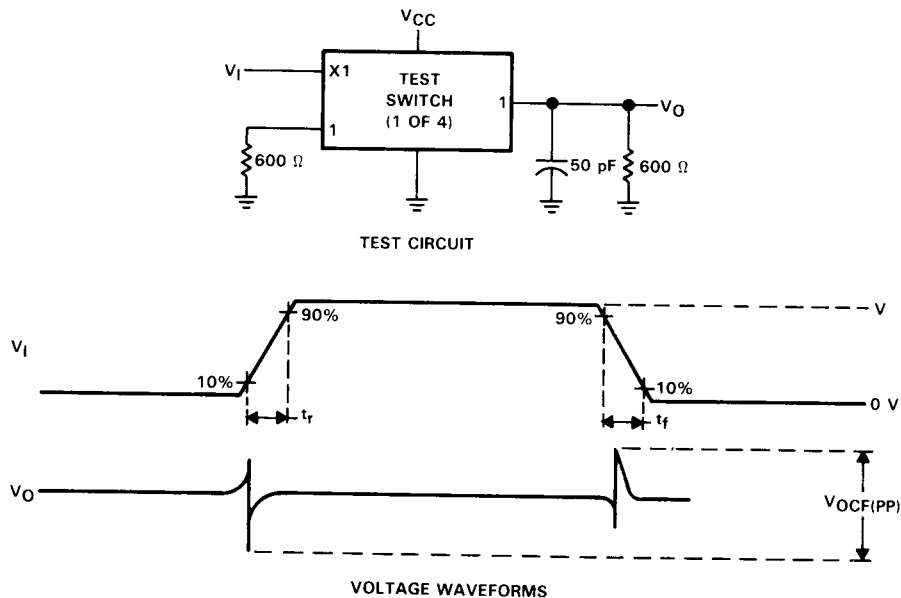


VOLTAGE WAVEFORMS

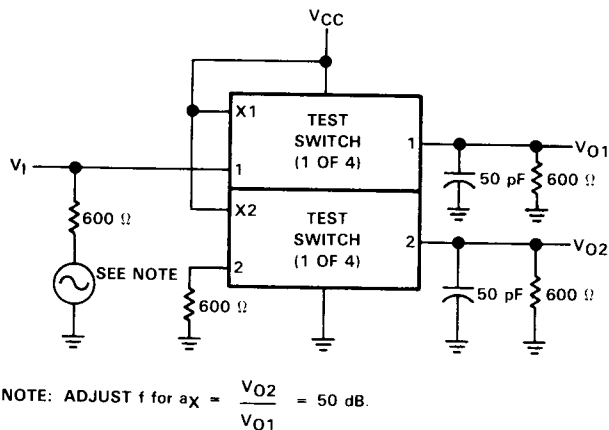
FIGURE 6. SWITCHING TIME ( $t_{pZH}$ ,  $t_{pHZ}$ ). CONTROL TO SIGNAL OUTPUT

**TLC4016M, TLC4016I**  
**SILICON-GATE CMOS QUADRUPLE BILATERAL ANALOG SWITCH**

**PARAMETER MEASUREMENT INFORMATION**



**FIGURE 7. CONTROL FEEDTHROUGH VOLTAGE**



**FIGURE 8. CROSSTALK BETWEEN ANY TWO SWITCHES, TEST CIRCUIT**